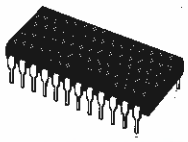
SGS-THOMSON MICROELECTRONICS

HCC/HCF4067B HCC/HCF4097B

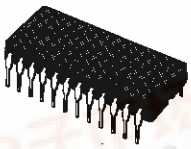
ANALOG MULTIPLEXER/DEMULTIPLEXER

4067B–SINGLE 16-CHANNEL
4097B–DIFFERENTIAL 8-CHANNEL

- LOW ON RESISTANCE: 125Ω (typ.) OVER 15 Vp-p SIGNAL INPUT RANGE FOR V_{DD} - V_{SS} = 15V
- HIGH OFF RESISTANCE: CHANNEL LEAKAGE OF ±10pA (typ.) @ V_{DD} - V_{SS} = 10V
- MATCHED SWITCH CHARACTERISTICS: ΔR_{ON} = 5Ω (typ.) FOR V_{DD} - V_{SS} = 15V
- VERY LOW QUIESCENT POWER DISSIPATION UNDER A DIGITAL CONTROL INPUT AND SUPPLY CONDITIONS: 0.2µW (typ.) @ V_{DD} -V_{SS} = 10V
- BINARY ADDRESS DECODING ON CHIP
- QUIESCENT CURRENT SPECIFIED TO 20V FOR HCC DEVICE
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT CURRENT OF 100nA AT 18V AND 25°C FOR HCC DEVICE
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC TENTATIVE STANDARD No 13A, "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIE CMOS DEVICES"



EY
(Plastic Package)



F
(Ceramic Package)

M1
(Micro Package)

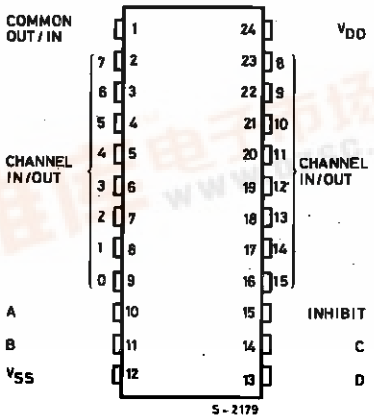
C1
(Chip Carrier)

ORDER CODES :

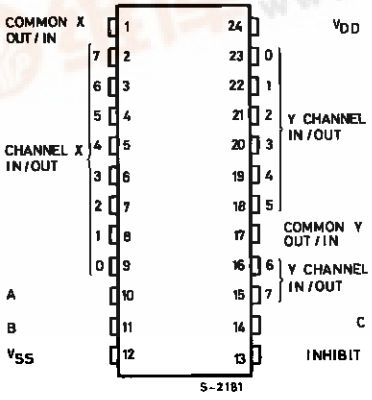
HCC40XXBF	HCF40XXBM1
HCF40XXBEY	HCF40XXBC1

PIN CONNECTIONS

4067B



4097B



DESCRIPTION

The **HCC4067B, HCC4097B** (extended temperature range) and **HCF4067B, HCF4097B** (intermediate temperature range) are monolithic integrated circuits available in 24-lead dual in line plastic or ceramic package.

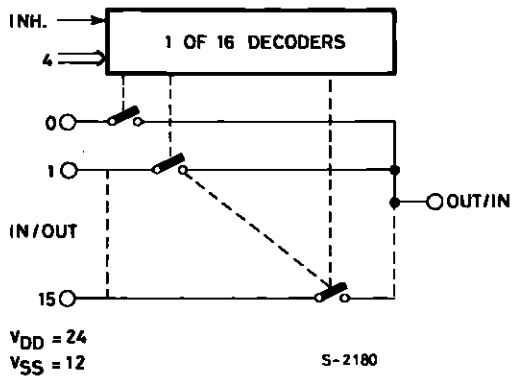
The **HCC/HCF4067B** and **HCC/HCF4097B** COS/MOS analog multiplexers/demultiplexers are digitally controlled analog switches having low ON impedance, low OFF leakage current and internal address decoding. in addition, the ON resistance is relatively constant over the full input-signal range.

The **HCC/HCF4067B** ia a 16-channel multiplexer with four binary control inputs A, B, C, D, and an inhibit input, arranged so that any combination of the inputs selects one switch.

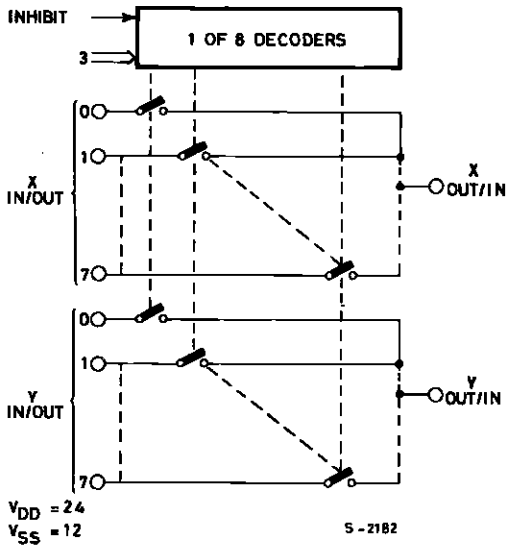
The **HCC/HCF4097** is a differential 8-channel multiplexer having three binary control inputs A, B, C, and an inhibit input. The inputs permit selection of one

FUNCTIONAL DIAGRAM

For **4067B**

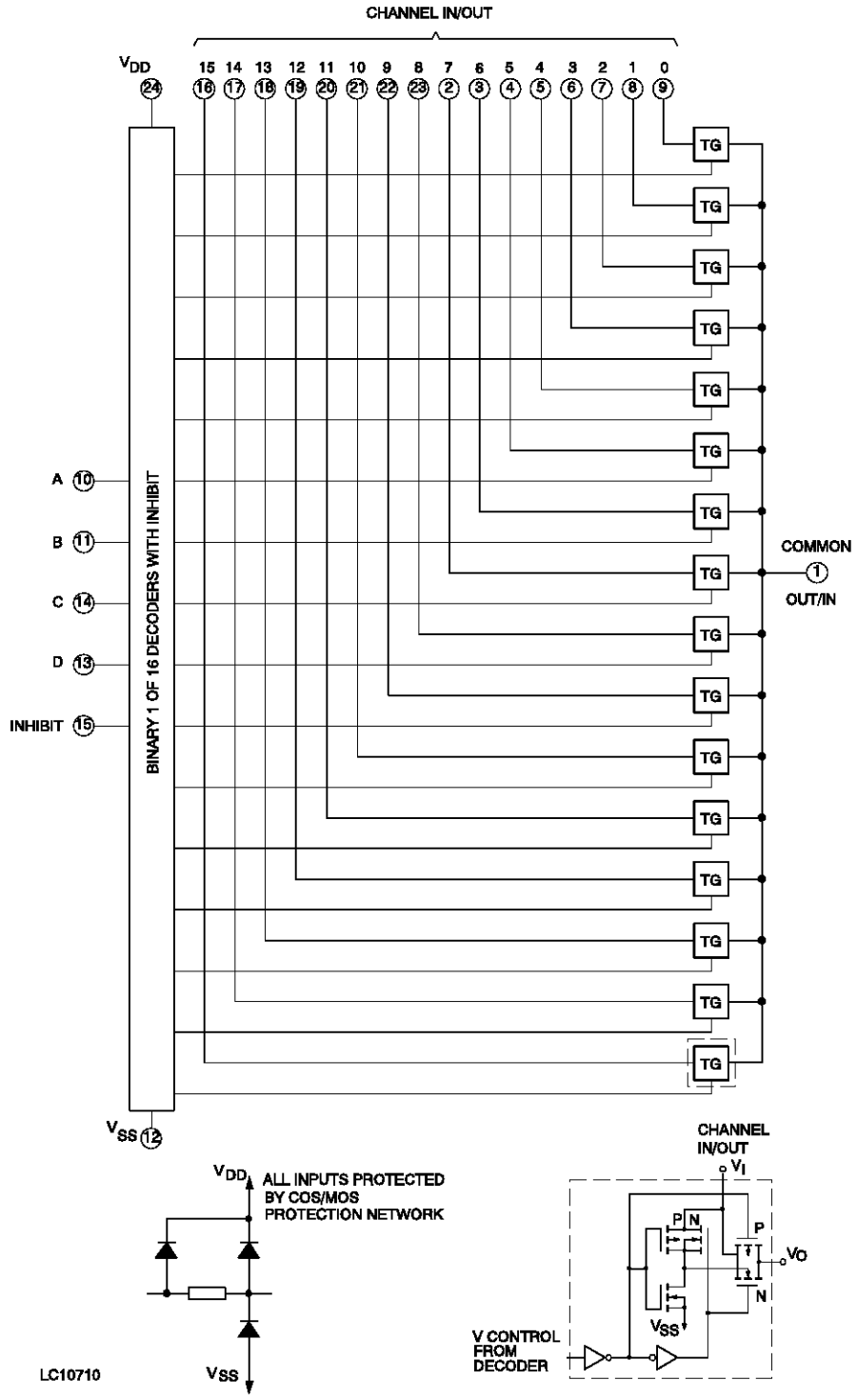


For **4097B**



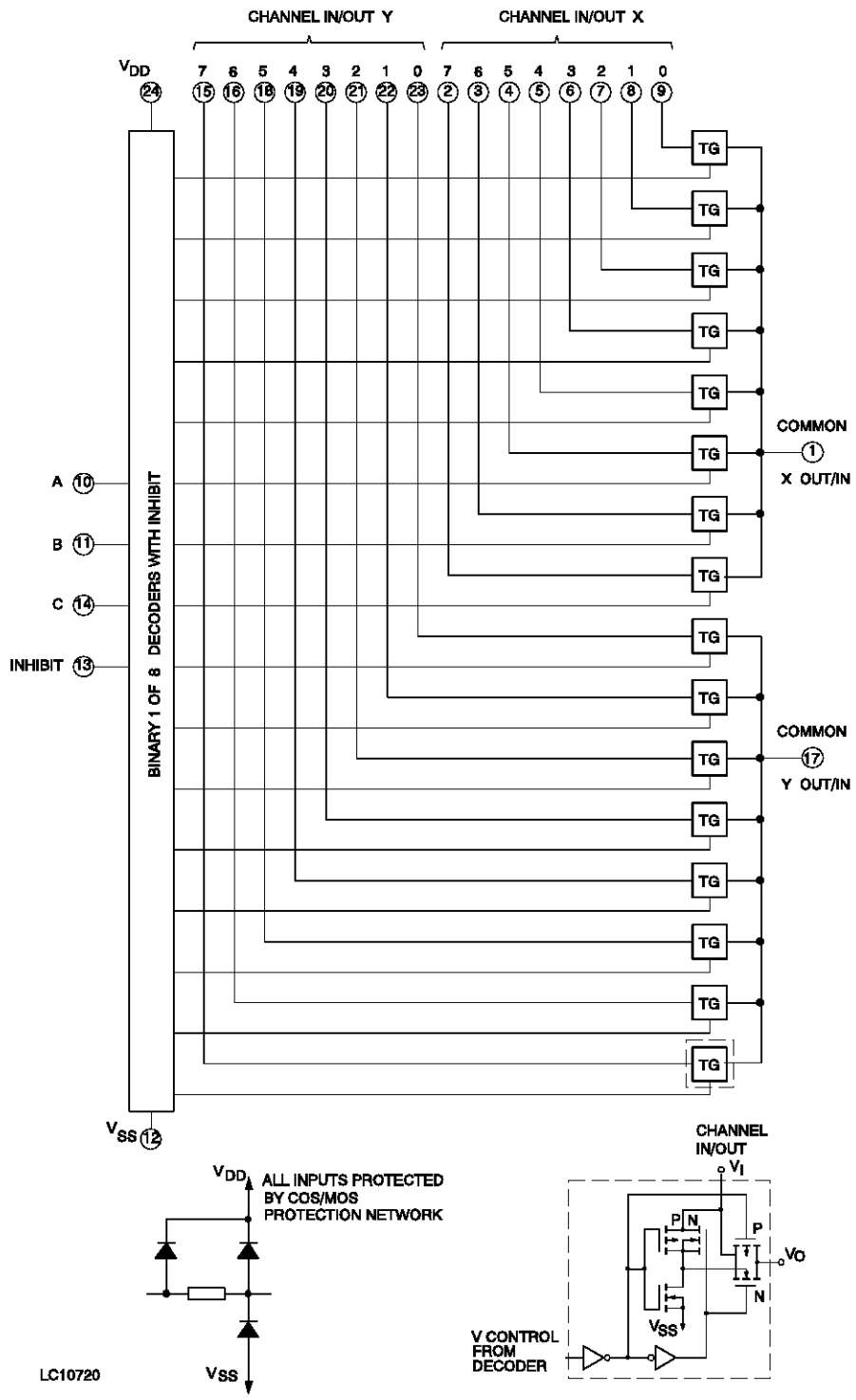
LOGIC DIAGRAM

For **4067B**



LOGIC DIAGRAM

For **4097B**



TRUTH TABLES FOR HCC/HCF4067B

A	B	C	D	INH	SELECTED CHANNEL
X	X	X	X	1	None
0	0	0	0	0	0
1	0	0	0	0	1
0	1	0	0	0	2
1	1	0	0	0	3
0	0	1	0	0	4
1	0	1	0	0	5
0	1	1	0	0	6
1	1	1	0	0	7
0	0	0	1	0	8
1	0	0	1	0	9
0	1	0	1	0	10
1	1	0	1	0	11
0	0	1	1	0	12
1	0	1	1	0	13
0	1	1	1	0	14
1	1	1	1	0	15

TRUTH TABLE FOR HCC/HCF4097B

A	B	C	INH	SELECTED CHANNEL
X	X	X	1	None
0	0	0	0	0X 0Y
1	0	0	0	1X 1Y
0	1	0	0	2X 2Y
1	1	0	0	3X 3Y
0	0	1	0	4X 4Y
1	0	1	0	5X 5Y
0	1	1	0	6X 6Y
1	1	1	0	7X 7Y

ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
V_{DD} *	Supply Voltage: **HCC** Types **HCF** Types	-0.5 to +20 -0.5 to +18	V V
V_i	Input Voltage	-0.5 to V_{DD} + 0.5	V
I_I	DC Input Current (any one input)	± 10	mA
P_{tot}	Total Power Dissipation (per package) Dissipation per Output Transistor for Top = Full Package Temperature Range	200 100	mW mW
T_{op}	Operating Temperature: **HCC** Types **HCF** Types	-55 to +125 -40 to +85	^oC ^oC
T_{stg}	Storage Temperature	-65 to +150	^oC

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for external periods may affect device reliability.

* All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage: **HCC** Types **HCF** Types	3 to 18 3 to 15	V V
V_I	Input Voltage	0 to V_{DD}	V
T_{op}	Operating Temperature: **HCC** Types **HCF** Types	-55 to +125 -40 to +85	^oC ^oC

STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

Symbol	Parameter		Test Conditios				Value							Unit
			V_{IS} (V)	V_{EE} (V)	V_{SS} (V)	V_{DD} (V)	T_{LOW} * Min.	T_{LOW} * Max.	25 °C Min.	25 °C Typ.	25 °C Max.	T_{HIGH} * Min.	T_{HIGH} * Max.	
I_L	Quiescent Supply Current	HCC types				5		5		0.04	5		150	µA
						10		10		0.04	10		300	
						15		20		0.04	20		600	
						20		100		0.08	100		3000	
		HCF types				5		20		0.04	20		150	
						10		40		0.04	40		300	
						15		80		0.04	80		600	
SWITCH														
R_{ON}	On Resistance	HCC types	$0 \le V_I \le V_{DD}$	0	0	5		800		470	1050		1300	Ω
						10		310		180	400		580	
						15		200		125	240		320	
		HCF types	$0 \le V_I \le V_{DD}$	0	0	5		850		470	1050		1200	
						10		330		180	400		520	
						15		210		125	240		300	
ΔON	Resistance ΔR_{ON} (Between any two channels)			0	0	5				10				Ω
						10				10				
						15				5				
OFF (•) Channel Leakage Current	Any Channel OFF	HCC types		0	0	18		100		±0.1	100		1000	µA
	All Channel OFF (common OUT/IN)	HCC types		0	0	18		100		±0.1	100		1000	
	Any Channel OFF	HCF types		0	0	15		300		±0.1	300		1000	
	All Channel OFF (common OUT/IN)	HCF types		0	0	15		300		±0.1	300		1000	
C	Capacitance Input Output for 4067 Output for 4097 Feedthrough				-5	5				5 55 35 0.2				pF
CONTROL														
V_{IL}	Input Low Voltage		= V_{DD} thru 1KΩ	$V_{EE}=V_{SS}$ R_L =1KΩ to V_{SS} I_{IS} < 2µA (on all OFF channels)		5		1.5			1.5		1.5	V
						10		3			3		3	
						15		4			4		4	
V_{IH}	Input High Voltage					5	3.5		3.5			3.5		V
						10	7		7			7		
						15	11		11			11		
I_{IH} I_{IL}	Input Leackage Current	HCC types	V_I = 0/18V			18		±0.1		$\pm 10^{-3}$	±0.1		±1	µA
		HCF types	V_I = 0/15V			15		±0.3		$\pm 10^{-3}$	±0.3		±1	
C_I	Input Capacitance		Any Address or Inhibit Input							5	7.5			pF

• Determined by minimum feasible leakage measurement for automatic testing

* T_{LOW} = -55 °C for **HCC** device: -40 °C for **HCF** device.

* T_{HIGH} = +125 °C for **HCC** device: +85 °C for **HCF** device.

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} = 5 V, 2 V min. with V_{DD} = 10 V, 2.5 V min. with V_{DD} = 15 V

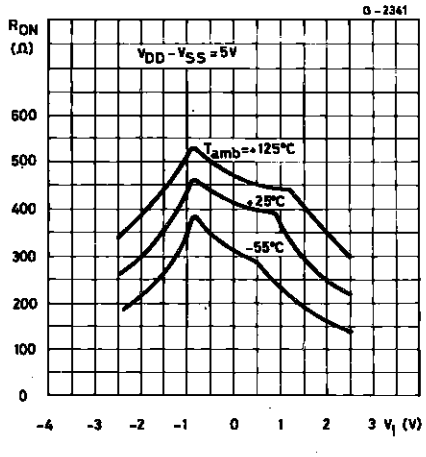
DYNAMIC ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, C_L = 50 pF, R_L = 200 KΩ, typical temperature coefficent for all V_{DD} values is 03 %/°C, all input rise and fall times= 20 ns)

Symbol	Parameter	Test Conditions								Value		Unit
		V_C (V)	R_L (KΩ)	f_i (KHz)	V_I (V)	V_{SS} (V)	V_{DD} (V)			Typ.	Max.	
SWITCH												
t_{pd}	Propagation Delay Time (Signal Input to Output)	= V_{DD}	200		⎍	0	5			30	60	ns
							10			15	30	
							15			11	20	
	Frequency Response Channel "ON" (Sine Wave Input) at $20\ Log \frac{V_O}{V_I} = -3\ dB$	= V_{DD}	1		5 (•)	0	10	V_O at Common OUT/IN	4067B	14		ns
									4097B	20		
								V_O at Any Channel		60		
	Feedthrough (All Channels OFF) at $20\ Log \frac{V_O}{V_I} = -40\ dB$	= V_{SS}	1		5 (•)	0	10	V_O at Common OUT/IN	4067B	20		MHz
									4097B	12		
								V_O at Any Channel		8		
	Frequency Signal Crosstalk at $20Log \frac{V_{O(B)}}{V_{I(A)}} = -40dB$	$V_{C(A)}$=V_{DD} $V_{C(B)}$=V_{SS}	1		5 (•)	0	10	Between Any two (A and B) Channels		1		MHz
								Between Sections (A and B) 4097B only	Measured on common	10		
									Measured on Any Channel	18		
t_W	Sine Wave Distortion (f_{is} = 1KHz sine wave)	5	10	1	2 (•)	0	5			0.3		%
		10	10	1	3 (•)	0	10			0.2		
		15	10	1	5 (•)	0	15			0.12		
CONTROL (address or Inhibit)												
t_{PLH} t_{PHL}	Propagation Delay Time: Address or Inhibit to Signal OUT (Channel Turning ON)	V_{DD} 0	1			0	5			325	650	ns
						0	10			135	270	
						0	15			95	190	
t_{PLH} t_{PHL}	Propagation Delay Time: Address or Inhibit to Signal OUT (Channel Turning OFF)	V_{DD} 0	0.3			0	5			220	440	ns
						0	10			90	180	
						0	15			65	130	
	Address or Inhibit to Signal Crosstalk	V_{DD} 0	10*			0	10			75		mV peak

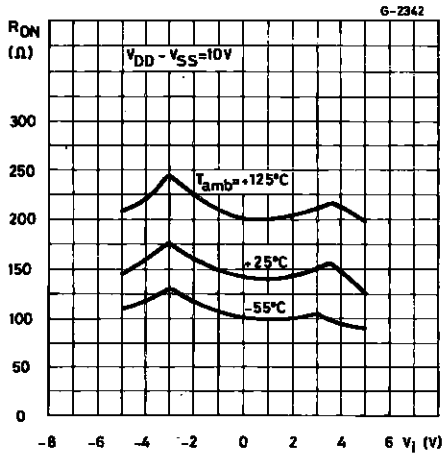
(•) Peak to peak voltage symmetrical about $\frac{V_{DD} - V_{SS}}{2}$

(*) Both ends of channel

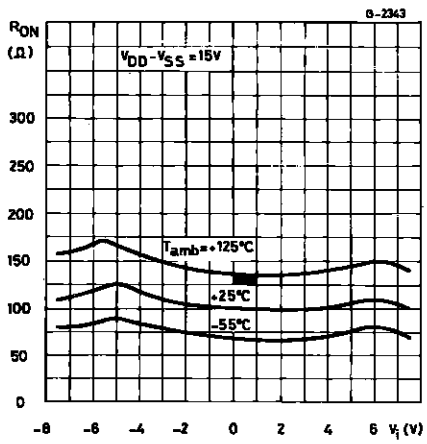
Typical ON Resistance vs Input Signal Voltage (All Types)



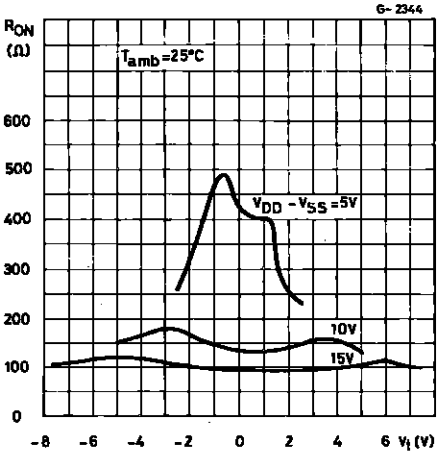
Typical ON Resistance vs Input Signal Voltage (All Types)



Typical ON Resistance vs Input Signal Voltage (All Types)



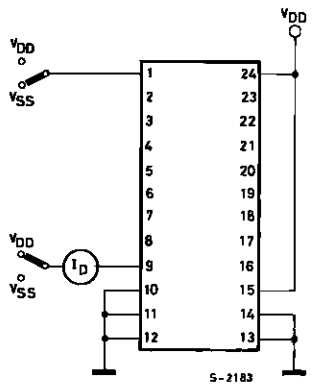
Typical ON Resistance vs Input Signal Voltage (All Types)



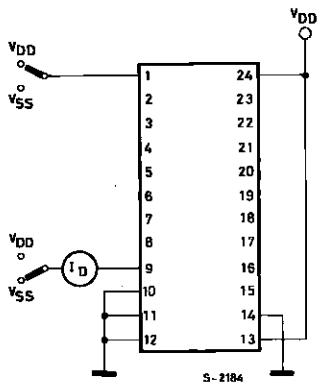
TEST CIRCUITS

OFF Channel Leakage Current Any Channel OFF

For **4067B**

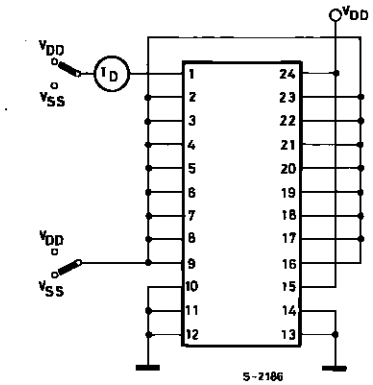


For **4097B**

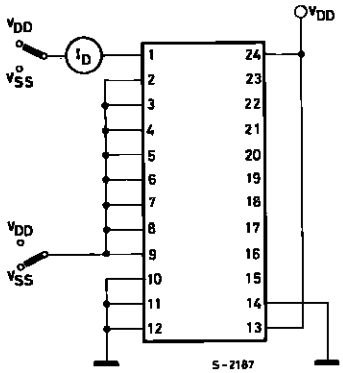


OFF Channel Leakage Current All Channels OFF

For **4067B**

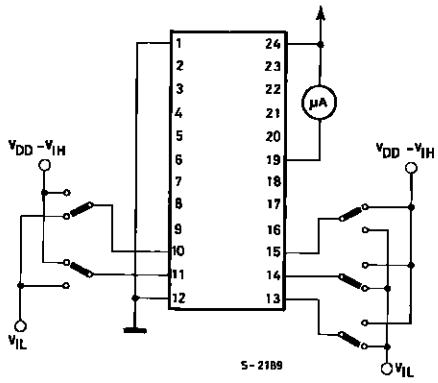


For **4097B**

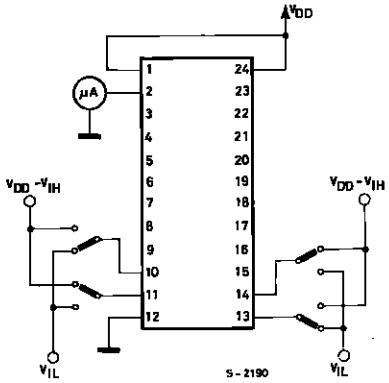


Input Voltage Measure < 2 µA an All OFF Channels (e.g. Channel 12)

For **4067B**

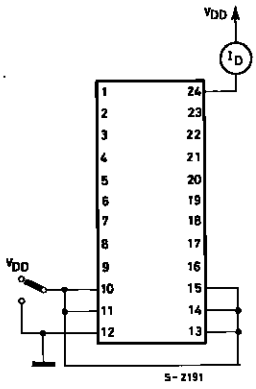


For **4097B**

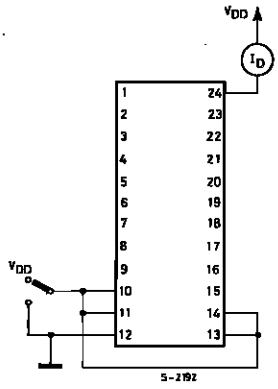


Quiescent Device Current

For **4067B**

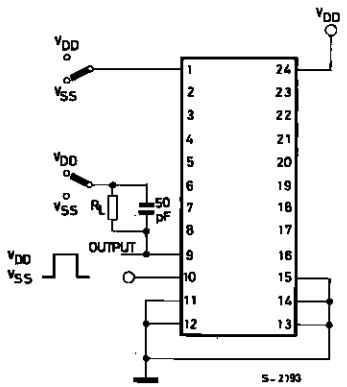


For **4097B**

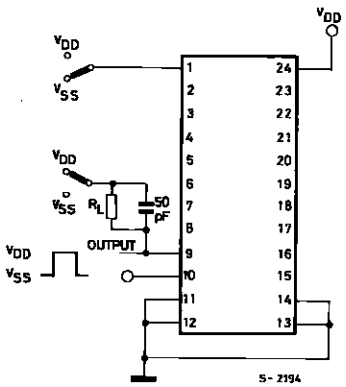


Turn-on and Turn-off Propagation Delay Address Select Input to Signal Output (e. g. Channel 0)

For **4067B**

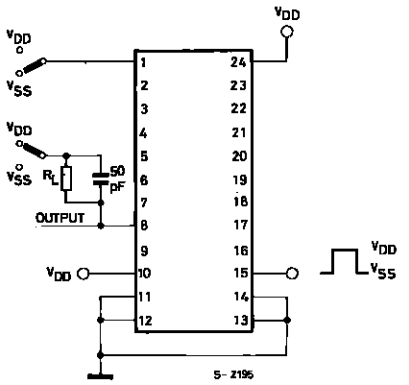


For **4097B**

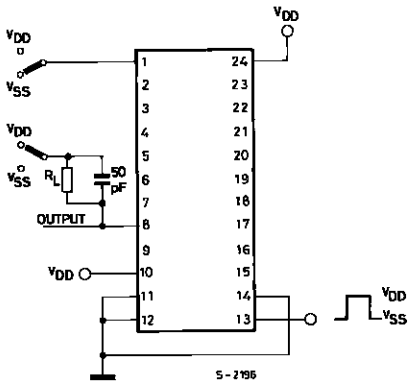


Turn-on and Turn-off Propagation Delay-Inhibit Input to Signal Output (e. g. Channel 1)

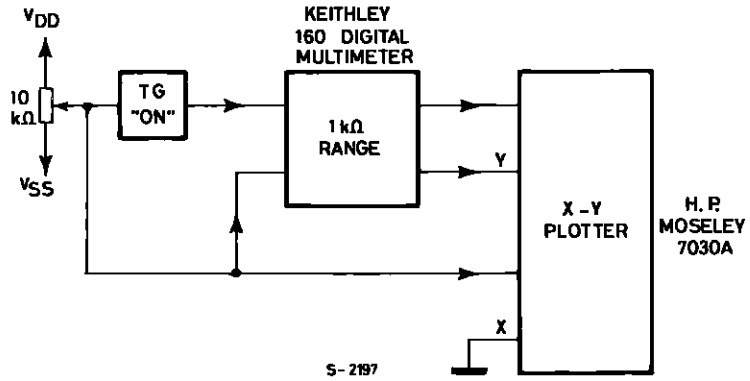
For **4067B**



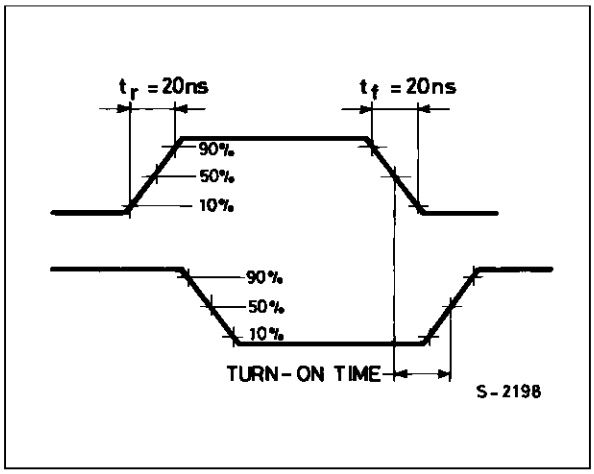
For **4097B**



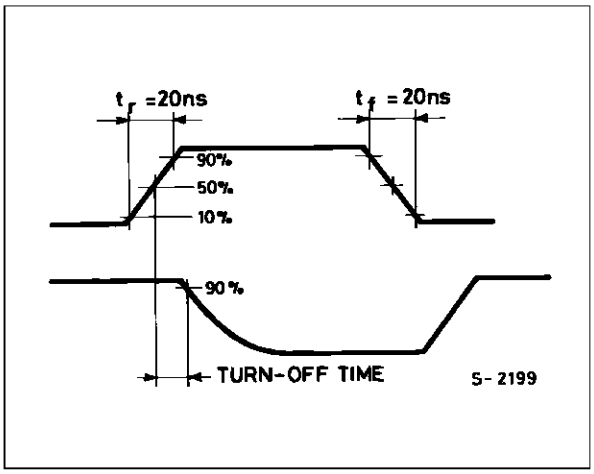
Channel ON Resistance Measurement Circuit



Propagation Delay Waveform Channel Being Turned ON (R_L = 10 KΩ, C_L = 50 pF)



Propagation Delay Waveform Channel Being Turned OFF (R_L = 300 Ω, C_L = 50 pF)



APPLICATIONS INFORMATION

In applications where separate power sources are used to drive V_{DD} and the signal inputs, the V_{DD} current capability should exceed V_{DD}/R_L (R_L = effective external load). This provision avoids permanent current flow or clamp action on the V_{DD} supply when power is applied or removed from the **HCC/HCF4067B** or **HCC/HCF4097B.**

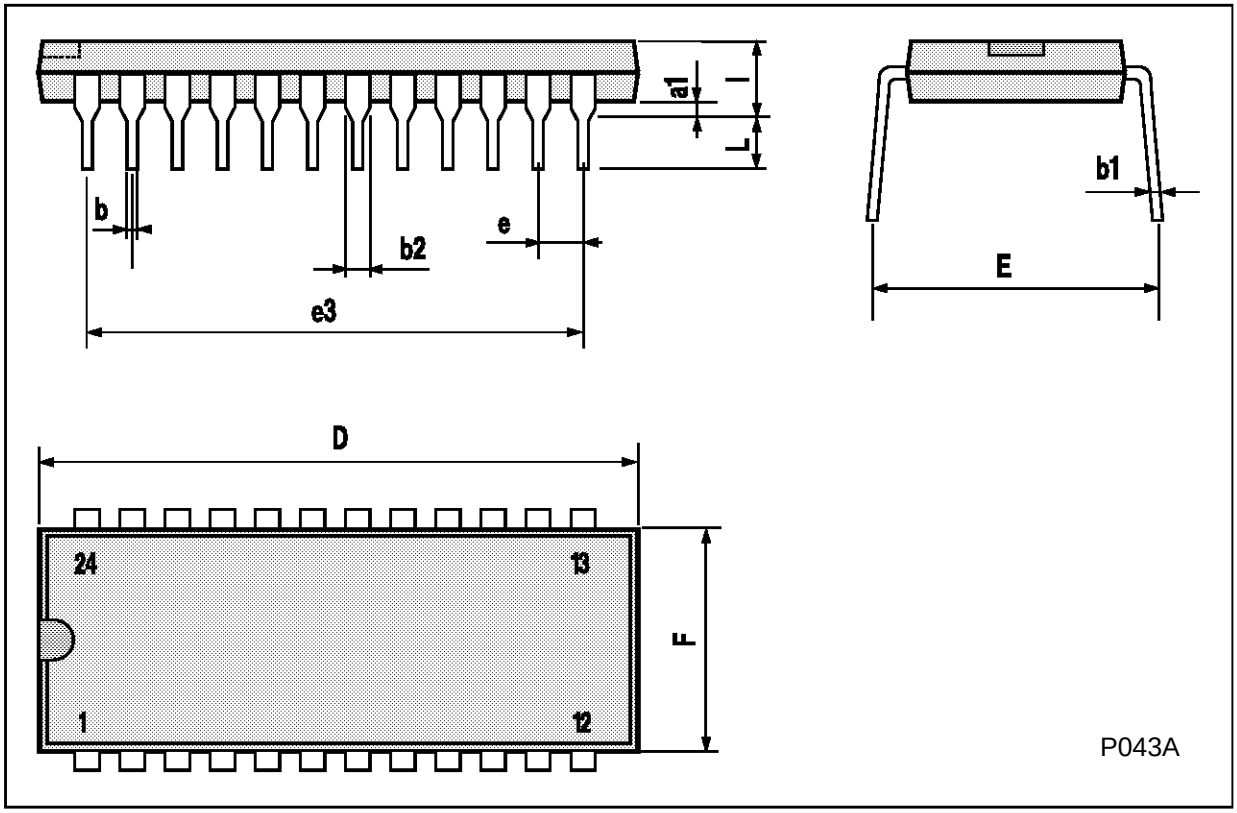
When switching from one address to another, some of the ON periods of the channels of the multiplexers will overlap momentarily, which may be objectionable in certain applications. Also when a channel is turned ON or OFF by an address input, there is a momentary conductive path from the channel to VSS, which will drump some charge from any capacitor connected to the input or output of the channel. The inhibit input turning on a channel will similarly drump some charge to V_{SS}.

The amount of charge dumped is mostly a function of the signal level above V_{SS}.
Typically, ay V_{DD} - V_{SS} = 10V, a 100 pF capacitor connected to the input or output of the channel will lose 3-4% of its voltage at the moment the channel turns ON or OFF. This loss of voltage is essentially independent of the address or inhibit signal trnasition time, if the transition time is less than 1- 2 µs. When the inhibit signal turns a channel off, there is no change dumping of V_{SS}. Rather, there is a slight rise in the channel voltage level (65 mV typ.) due to the capacitance coupling from inhibit input to channel input or output. Address input also couple some voltage steps onto the channel signal levels.

In certain applications, the external load-resistor current may include both V_{DD} and signal line components. To avoid drawing V_{DD} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.8 V (calculated from R_{ON} values shown in ELECTRICAL CHARACTERISTICS CHART). No VDD current will flow through R_L if the switch current flows into terminal 1 on the **HCC/HCF4067B**, terminals 1 and 17 on the **HCC/HCF4097B.**

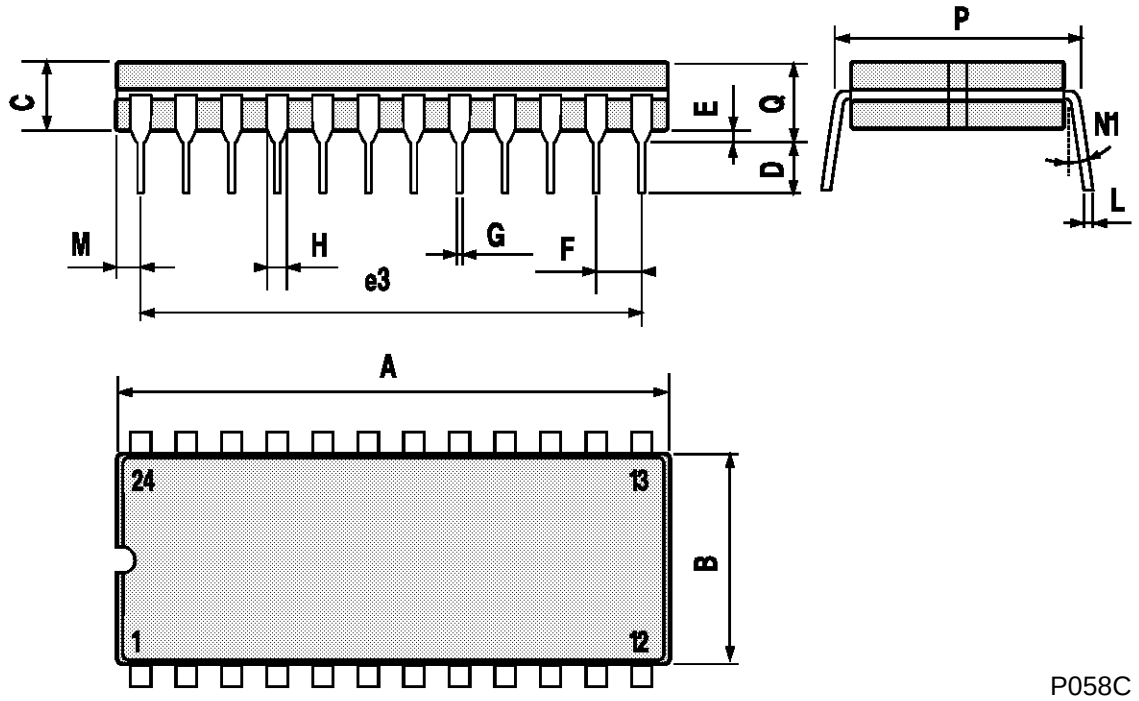
Plastic DIP24 (0.25) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1		0.63			0.025	
b		0.45			0.018	
b1	0.23		0.31	0.009		0.012
b2		1.27			0.050	
D			32.2			1.268
E	15.2		16.68	0.598		0.657
e		2.54			0.100	
e3		27.94			1.100	
F			14.1			0.555
I		4.445			0.175	
L		3.3			0.130	



Ceramic DIP24 MECHANICAL DATA

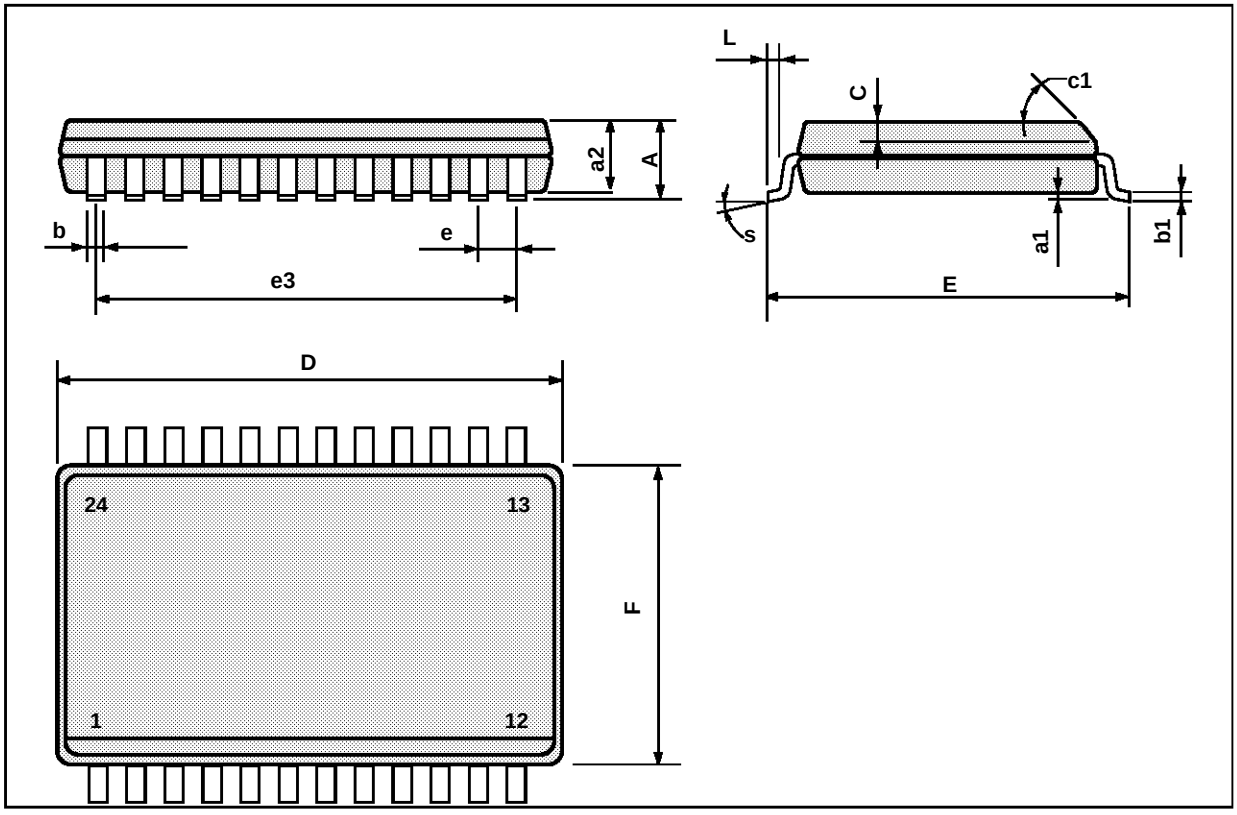
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			32.3			1.272
B	13.05		13.36	0.514		0.526
C	3.9		5.08	0.154		0.200
D	3			0.118		
E	0.5		1.78	0.020		0.070
e3		27.94			1.100	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
I	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	1.52		2.49	0.060		0.098
N1	4° (min.), 15° (max.)					
P	15.4		15.8	0.606		0.622
Q			5.71			0.225



P058C

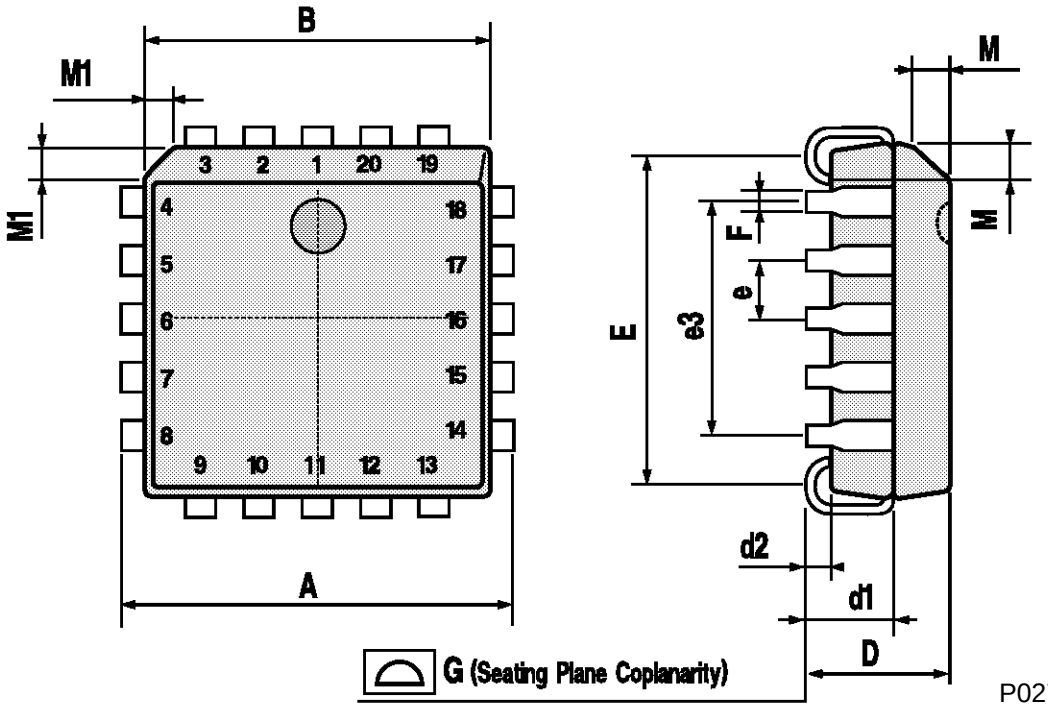
SO24 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.10		0.20	0.004		0.007
a2			2.45			0.096
b	0.35		0.49	0.013		0.019
b1	0.23		0.32	0.009		0.012
C		0.50			0.020	
c1	45° (typ.)					
D	15.20		15.60	0.598		0.614
E	10.00		10.65	0.393		0.420
e		1.27			0.05	
e3		13.97			0.55	
F	7.40		7.60	0.291		0.299
L	0.50		1.27	0.19		0.050
S	8° (max.)					



PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



P027A